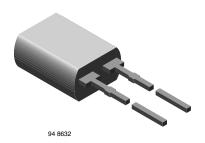


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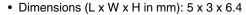
Silicon PIN Photodiode



FEATURES

Package type: leaded





• Radiant sensitive area (in mm²): 7.5

· High photo sensitivity

· High radiant sensitivity

• Suitable for visible and near infrared radiation

• Fast response times

• Angle of half sensitivity: $\varphi = \pm 65^{\circ}$

· Material categorization: for definitions of compliance please see www.vishav.com/doc?99912





HALOGEN

FREE **GREEN**

DESCRIPTION

BPW46 is a PIN photodiode with high speed and high radiant sensitivity in a clear, side view plastic package. It is sensitive to visible and near infrared radiation.

APPLICATIONS

· High speed photo detector

| PRODUCT SUMMARY | | | |
|-----------------|----------------------|---------|-----------------------|
| COMPONENT | I _{ra} (μΑ) | φ (deg) | λ _{0.1} (nm) |
| BPW46 | 50 | ± 65 | 430 to 1100 |

Note

· Test condition see table "Basic Characteristics"

| ORDERING INFORMATION | | | | |
|----------------------|-----------|------------------------------|--------------|--|
| ORDERING CODE | PACKAGING | REMARKS | PACKAGE FORM | |
| BPW46 | Bulk | MOQ: 4000 pcs, 4000 pcs/bulk | Side view | |

Note

· MOQ: minimum order quantity

| ABSOLUTE MAXIMUM RATINGS (T _{amb} = 25 °C, unless otherwise specified) | | | | | |
|--|--|-------------------|-------------|------|--|
| PARAMETER | TEST CONDITION | SYMBOL | VALUE | UNIT | |
| Reverse voltage | | V _R | 60 | V | |
| Power dissipation | T _{amb} ≤ 25 °C | P _V | 215 | mW | |
| Junction temperature | | T _j | 100 | °C | |
| Operating temperature range | | T _{amb} | -40 to +100 | °C | |
| Storage temperature range | | T _{stg} | -40 to +100 | °C | |
| Soldering temperature | t ≤ 5 s | T _{sd} | 260 | °C | |
| Thermal resistance junction/ambient | Connected with Cu wire, 0.14 mm ² | R _{thJA} | 350 | K/W | |



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| BASIC CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified) | | | | | | |
|---|---|-------------------|------|-----------------------|------|-------|
| PARAMETER | TEST CONDITION | SYMBOL | MIN. | TYP. | MAX. | UNIT |
| Breakdown voltage | I _R = 100 μA, E = 0 | V _(BR) | 60 | | | V |
| Reverse dark current | V _R = 10 V, E = 0 | I _{ro} | | 2 | 30 | nA |
| Diode capacitance | V _R = 0 V, f = 1 MHz, E = 0 | C _D | | 70 | | pF |
| | V _R = 3 V, f = 1 MHz, E = 0 | C _D | | 25 | 40 | pF |
| Open circuit voltage | $E_{e} = 1 \text{ mW/cm}^{2}, \lambda = 950 \text{ nm}$ | Vo | | 350 | | mV |
| Temperature coefficient of Vo | $E_{e} = 1 \text{ mW/cm}^{2}, \lambda = 950 \text{ nm}$ | TK _{Vo} | | -2.6 | | mV/K |
| 0 | E _A = 1 klx | l _k | | 70 | | μΑ |
| Short circuit current | $E_e = 1 \text{ mW/cm}^2, \lambda = 950 \text{ nm}$ | l _k | | 47 | | μΑ |
| Temperature coefficient of I _k | $E_{e} = 1 \text{ mW/cm}^{2}, \lambda = 950 \text{ nm}$ | TK _{lk} | | 0.1 | | %/K |
| Reverse light current | E _A = 1 klx, V _R = 5 V | I _{ra} | | 75 | | μΑ |
| | E_e = 1 mW/cm ² , λ = 950 nm, V_R = 5 V | I _{ra} | 40 | 50 | | μΑ |
| Angle of half sensitivity | | φ | | ± 65 | | deg |
| Wavelength of peak sensitivity | | λ_{p} | | 900 | | nm |
| Range of spectral bandwidth | | λ _{0.1} | | 430 to 1100 | | nm |
| Noise equivalent power | $V_R = 10 \text{ V}, \lambda = 950 \text{ nm}$ | NEP | | 4 x 10 ⁻¹⁴ | | W/√Hz |
| Rise time | $V_R = 10 \text{ V}, R_L = 1 \text{ k}\Omega, \lambda = 820 \text{ nm}$ | t _r | | 100 | | ns |
| Fall time | $V_R = 10 \text{ V}, R_L = 1 \text{ k}\Omega, \lambda = 820 \text{ nm}$ | t _f | | 100 | | ns |

BASIC CHARACTERISTICS (T_{amb} = 25 °C, unless otherwise specified)

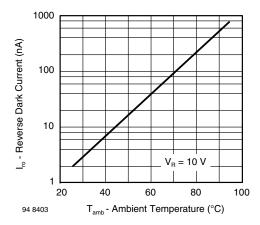


Fig. 1 - Reverse Dark Current vs. Ambient Temperature

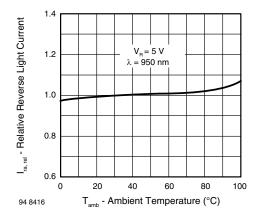


Fig. 2 - Relative Reverse Light Current vs. Ambient Temperature



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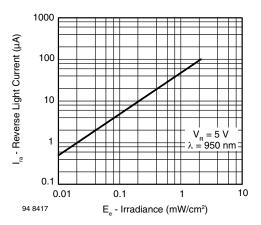


Fig. 3 - Reverse Light Current vs. Irradiance

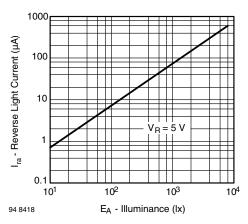


Fig. 4 - Reverse Light Current vs. Illuminance

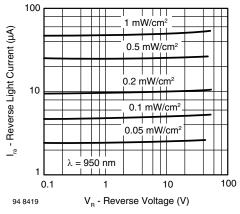


Fig. 5 - Reverse Light Current vs. Reverse Voltage

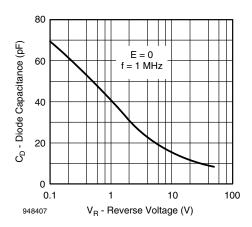


Fig. 6 - Diode Capacitance vs. Reverse Voltage

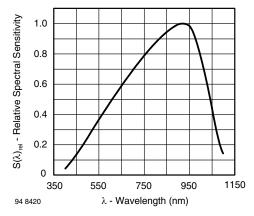


Fig. 7 - Relative Spectral Sensitivity vs. Wavelength

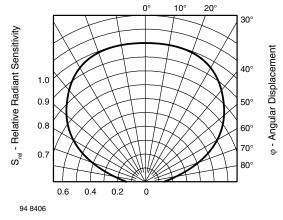
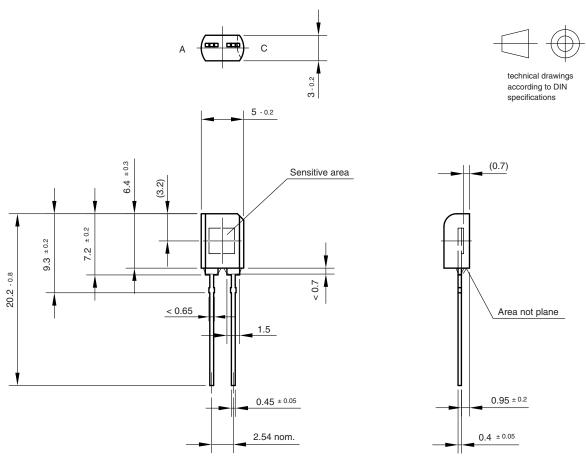


Fig. 8 - Relative Radiant Sensitivity vs. Angular Displacement



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PACKAGE DIMENSIONS in millimeters



Drawing-No.: 6.544-5109.01-4

Issue:1; 01.07.96

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